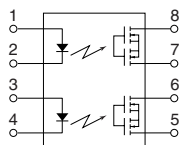
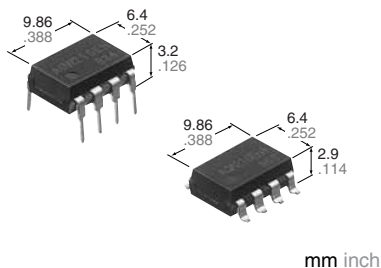


General use and economy type.
DIP (2 Form A) 8-pin type.
Reinforced insulation
5,000V type.

GU-E PhotoMOS (AQW210EH)



FEATURES

- 1. Reinforced insulation 5,000 V type**
More than 0.4 mm internal insulation distance between inputs and outputs. Con-forms to EN41003, EN60950 (reinforced insulation).
- 2. Compact 8-pin DIP size**
The device comes in a compact (W)6.4×(L)9.86×(H)3.2 mm (W).252×(L).388×(H).126 inch, 8-pin DIP size (through hole terminal type).
- 3. Applicable for 2 Form A use as well as two independent 1 Form A use**
- 4. Controls low-level analog signals**
PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

- 5. High sensitivity, high speed response.**
Can control a maximum 0.14 A load current with a 5 mA input current. Fast operation speed of 0.5 ms (typical). (AQW210EH)
- 6. Low-level off state leakage current**

RoHS Directive compatibility information
<http://www.mew.co.jp/ac/e/environment/>

TYPICAL APPLICATIONS

- Modem
- Telephone equipment
- Security equipment
- Sensors

TYPES

Type	I/O isolation voltage	Output rating*		Part No.				Packing quantity	
				Through hole terminal	Surface-mount terminal				
		Load voltage	Load current	Tube packing style		Tape and reel packing style		Tube	Tape and reel
AC/DC type	Reinforced 5,000 V	60 V	500 mA	AQW212EH	AQW212EHA	AQW212EHAX	AQW212EHAZ		
		350 V	120 mA	AQW210EH	AQW210EHA	AQW210EHAX	AQW210EHAZ		
		400 V	100 mA	AQW214EH	AQW214EHA	AQW214EHAX	AQW214EHAZ		
		600 V	40 mA	AQW216EH	AQW216EHA	AQW216EHAX	AQW216EHAZ		

*Indicate the peak AC and DC values.

Note: For space reasons, the SMD terminal shape indicator "A" and the package style indicator "X" or "Z" are not marked on the relay.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQW212EH(A)	AQW210EH(A)	AQW214EH(A)	AQW216EH(A)	Remarks
Input	LED forward current	I _F	50mA				
	LED reverse voltage	V _R	5V				
	Peak forward current	I _{FP}	1A				f = 100 Hz, Duty factor = 0.1%
	Power dissipation	P _{in}	75mW				
Output	Load voltage (peak AC)	V _L	60 V	350 V	400 V	600 V	
	Continuous load current (peak AC)	I _L	0.5 A (0.6 A)	0.12 A (0.14 A)	0.1 A (0.13 A)	0.04 A (0.05 A)	Peak AC, DC (): in case of using only 1 channel
	Peak load current	I _{peak}	1.5 A	0.36 A	0.3 A	0.15 A	100 ms (1 shot), V _L = DC
	Power dissipation	P _{out}	800mW				
Total power dissipation		P _T	850mW				
I/O isolation voltage		V _{iso}	5,000 V AC				
Temperature limits	Operating	T _{opr}	-40°C to +85°C -40°F to +185°F				Non-condensing at low temperatures
	Storage	T _{stg}	-40°C to +100°C -40°F to +212°F				

GU-E PhotoMOS (AQW21○EH)

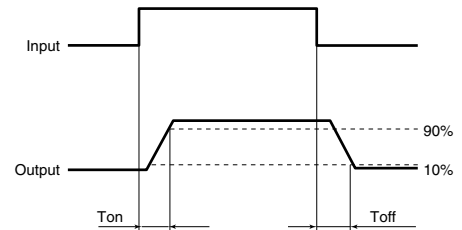
2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	AQW212EH(A)	AQW210EH(A)	AQW214EH(A)	AQW216EH(A)	Condition
Input	LED operate current	Typical	1.2mA				I _L =Max.
		Maximum	3.0mA				
	LED turn off current	Minimum	0.4mA				I _L =Max.
		Typical	1.1mA				
LED dropout voltage	Typical	V _F	1.25 V (1.14 V at I _F =5mA)				I _F =50mA
	Maximum		1.5V				
Output	On resistance	Typical	0.83Ω	18Ω	26Ω	52Ω	I _F =5mA I _L =Max. Within 1 s on time
		Maximum	2.5Ω	25Ω	35Ω	120Ω	
	Off state leakage current	Maximum	I _{Leak}	1μA			
Transfer characteristics	Turn on time*	Typical	1ms	0.5ms			I _F =5mA I _L =Max.
		Maximum	4ms	2.0ms			
	Turn off time*	Typical	0.08ms			0.04ms	I _F =5mA I _L =Max.
		Maximum	1.0ms				
	I/O capacitance	Typical	0.8pF				f = 1MHz V _B = 0V
Maximum		1.5pF					
Initial I/O isolation resistance	Minimum	R _{iso}	1,000MΩ			500V DC	

Note: Recommendable LED forward current I_F= 5 to 10mA.

For type of connection.

*Turn on/Turn off time

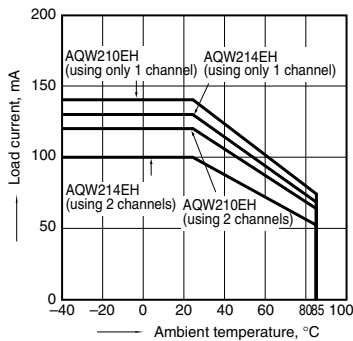


- For Dimensions.
- For Schematic and Wiring Diagrams.
- For Cautions for Use.

REFERENCE DATA

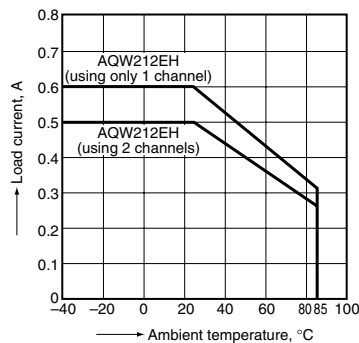
1-(1). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -20°C to +85°C
-4°F to +185°F



1-(2). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F



1-(3). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F

